

SURFACE MOUNT GLASS PASSIVATED RECTIFIERS

REVERSE VOLTAGE - 50 to 1000Volts
FORWARD CURRENT - 3.0 Amperes

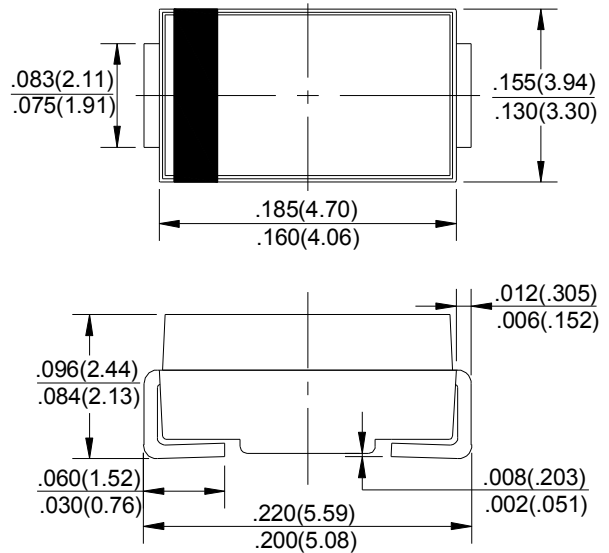
FEATURES

- Glass passivated chip
- For surface mounted applications
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Case: Molded Plastic
- Polarity: Color band denotes cathode
- Weight: 0.003 ounces, 0.093 grams
- Mounting position: Any

SMB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	S3AB	S3BB	S3DB	S3GB	S3JB	S3KB	S3MB	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @T _L =75 °C	I _(AV)	3.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed On Rated Load (JEDEC Method)	I _{FSM}	100							A
Maximum Forward Voltage at 3.0A DC	V _F	1.1							V
Maximum DC Reverse Current @T _J =25°C at Rated DC Blocking Voltage @T _J =125°C	I _R	5.0 250							μA
Typical Junction Capacitance (Note1)	C _J	40							pF
Typical Thermal Resistance (Note2)	R _{θJL}	10							°C/W
Typical Thermal Resistance (Note3)	R _{θJA}	50							°C/W
Operating Temperature Range	T _J	-55 to +150							°C
Storage Temperature Range	T _{STG}	-55 to +150							°C

NOTES:1.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

2.Thermal resistance junction to lead.

3.Thermal resistance junction to ambient.

FIG. 1 - FORWARD CURRENT DERATING CURVE

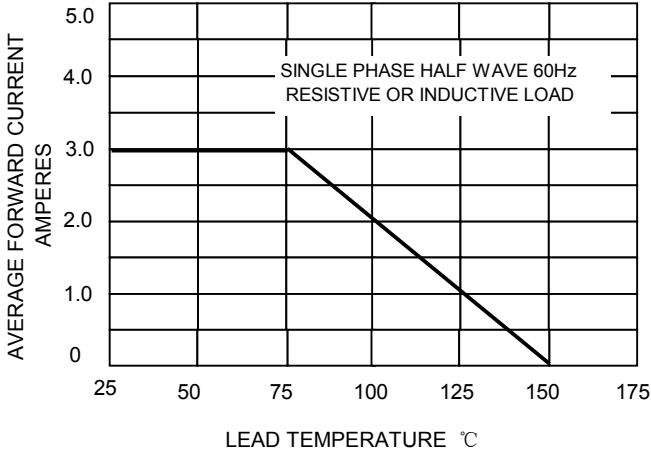


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

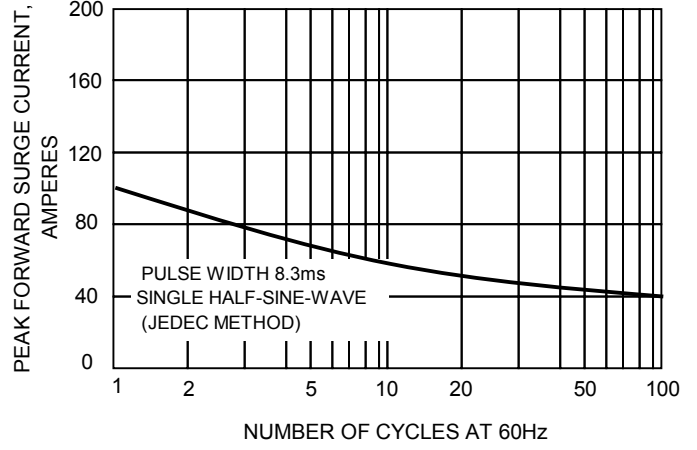


FIG.3-TYPICAL FORWARD CHARACTERISTICS

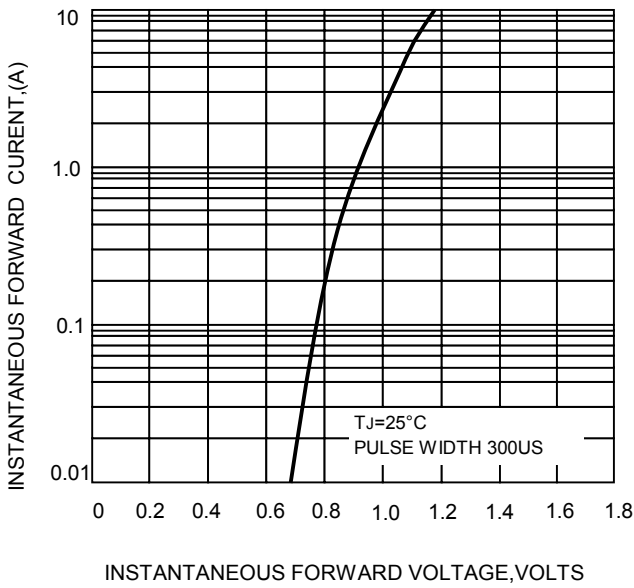


FIG.4-TYPICAL REVERSE CHARACTERISTICS

